NSN 5961-01-036-1274

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-036-1274 **Inclosure Material:** Glass **Overall Length:** 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **Function For Which Designed:** General purpose **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 4.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 475.0 milliwatts large-signal input power, common-emitter absolute **Capacitance Rating In Picofarads:** 2.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 06481-932354 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**